Memory Microcircuit - Page 1 of 1

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## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# Features Provided:

Programmed

### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

# Case Outline Source And Designator:

D-8 mil-m-38510

#### **Product Name:**

116-input 6-output registered and-or gate array

# Voltage Rating And Type Per Characteristic:

4.5 volts applied and 5.5 volts applied

## Memory Device Type:

Pal

#### Hybrid Technology Type:

Monolithic

# **Terminal Type And Quantity:**

20 printed circuit

#### **Specification Data:**

81349--38510/50607bra government specification and 67268-5962-8515507ra government standard

#### **Departure From Cited Designator:**

Altered by programming & testing

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

#### Fiig:

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